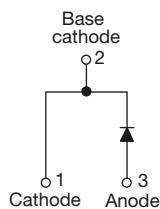


## HEXFRED®, Ultrafast Soft Recovery Diode, 15 A



### FEATURES

- Ultrafast and ultrasoft recovery
- Very low  $I_{RRM}$  and  $Q_{rr}$
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization:  
for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

### DESCRIPTION

VS-HFA15TB60... is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 15 A continuous current, the VS-HFA15TB60... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current ( $I_{RRM}$ ) and does not exhibit any tendency to "snap-off" during the  $t_b$  portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA15TB60... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	15 A
$V_R$	600 V
$V_F$ at $I_F$	1.2 V
$t_{rr}$ typ.	23 ns
$T_J$ max.	150 °C
Circuit configuration	Single
Package	TO-220AC 2L

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Cathode to anode voltage	$V_R$		600	V
Maximum continuous forward current	$I_F$	$T_C = 100$ °C	15	A
Single pulse forward current	$I_{FSM}$		150	
Maximum repetitive forward current	$I_{FRM}$		60	W
Maximum power dissipation	$P_D$	$T_C = 25$ °C	74	
		$T_C = 100$ °C	29	
Operating junction and storage temperature range	$T_J, T_{Stg}$		-55 to +150	°C

**ELECTRICAL SPECIFICATIONS** ( $T_J = 25^\circ\text{C}$  unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	$V_{BR}$	$I_R = 100 \mu\text{A}$		600	-	-	V
Maximum forward voltage	$V_{FM}$	$I_F = 15 \text{ A}$	See fig. 1	-	1.3	1.7	
		$I_F = 30 \text{ A}$		-	1.5	2.0	
		$I_F = 15 \text{ A}, T_J = 125^\circ\text{C}$		-	1.2	1.6	
Maximum reverse leakage current	$I_{RM}$	$V_R = V_R \text{ rated}$ $T_J = 125^\circ\text{C}, V_R = 0.8 \times V_R \text{ rated}$	See fig. 2	-	1.0	10	$\mu\text{A}$
				-	400	1000	
Junction capacitance	$C_T$	$V_R = 200 \text{ V}$	See fig. 3	-	25	50	pF
Series inductance	$L_S$	Measured lead to lead 5 mm from package body		-	8.0	-	nH

**DYNAMIC RECOVERY CHARACTERISTICS** ( $T_J = 25^\circ\text{C}$  unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time See fig. 5	$t_{rr}$	$I_F = 1.0 \text{ A}, di_F/dt = 200 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$		-	19	-	ns
	$t_{rr1}$	$T_J = 25^\circ\text{C}$	See fig. 1 $I_F = 15 \text{ A}$ $di_F/dt = 200 \text{ A}/\mu\text{s}$ $V_R = 200 \text{ V}$	-	42	60	
	$t_{rr2}$	$T_J = 125^\circ\text{C}$		-	74	120	
Peak recovery current See fig. 6	$I_{RRM1}$	$T_J = 25^\circ\text{C}$		-	4.0	6.0	A
	$I_{RRM2}$	$T_J = 125^\circ\text{C}$		-	6.5	10	
	$Q_{rr1}$	$T_J = 25^\circ\text{C}$		-	84	180	nC
Reverse recovery charge See fig. 7	$Q_{rr2}$	$T_J = 125^\circ\text{C}$		-	241	600	
	$di_{(rec)M}/dt1$	$T_J = 25^\circ\text{C}$		-	188	-	A/ $\mu\text{s}$
	$di_{(rec)M}/dt2$	$T_J = 125^\circ\text{C}$		-	160	-	

**THERMAL - MECHANICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
Lead temperature	$T_{lead}$	0.063" from case (1.6 mm) for 10 s		-	-	300	$^\circ\text{C}$	
Thermal resistance, junction to case	$R_{thJC}$	Typical socket mount		-	-	1.7	K/W	
Thermal resistance, junction to ambient	$R_{thJA}$			-	-	80		
Weight				-	2.0	-	g	
				-	0.07	-	oz.	
Mounting torque				6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style 2L TO-220AC		HFA15TB60				

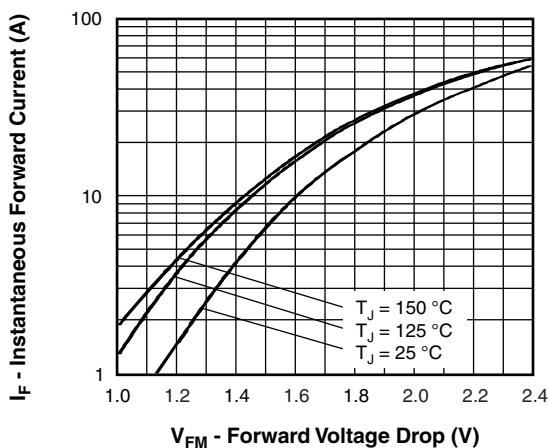


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

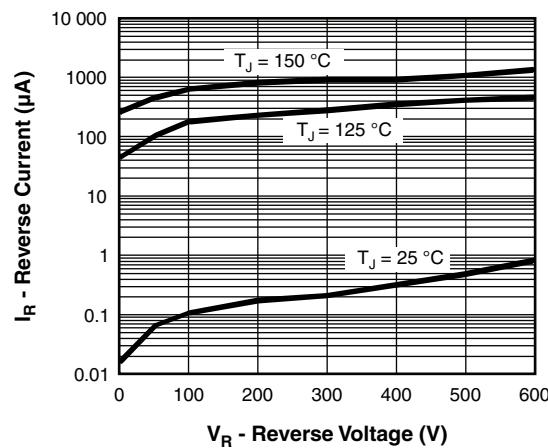


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

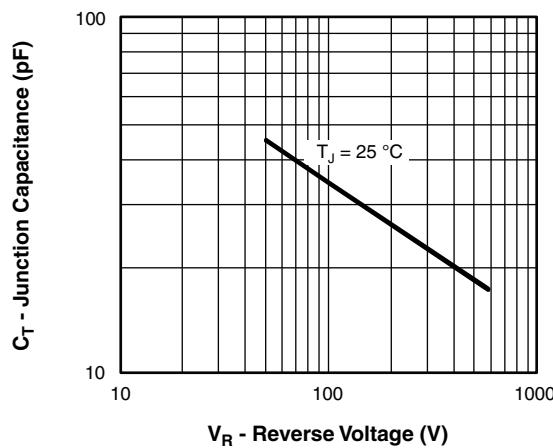


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

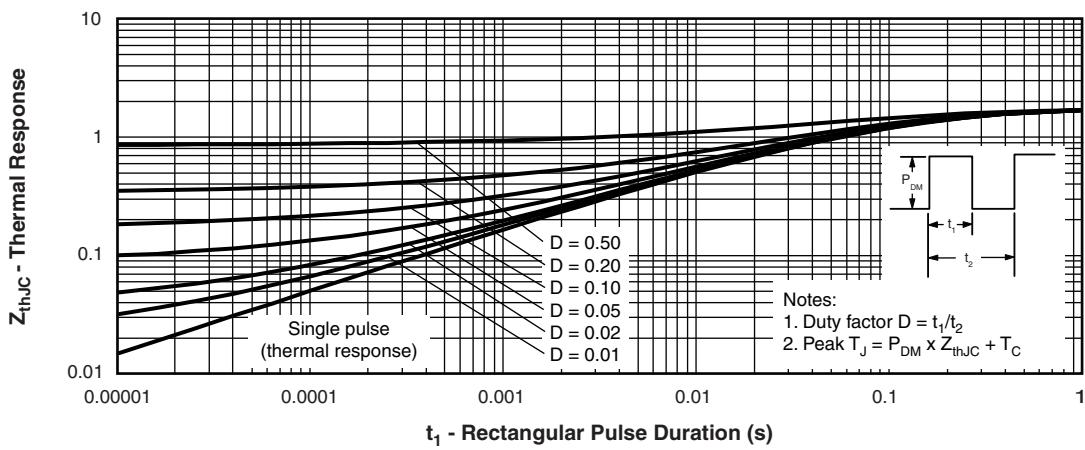


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

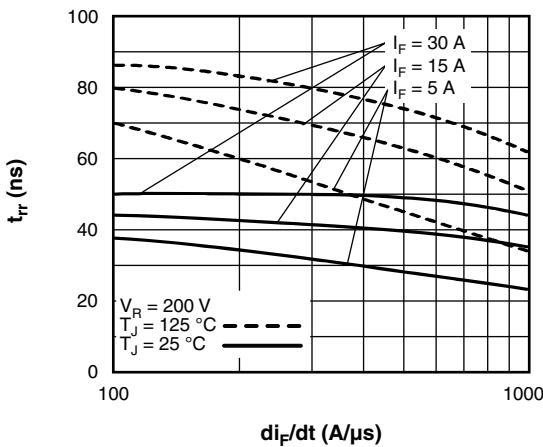


Fig. 5 - Typical Reverse Recovery Time vs.  $di_F/dt$

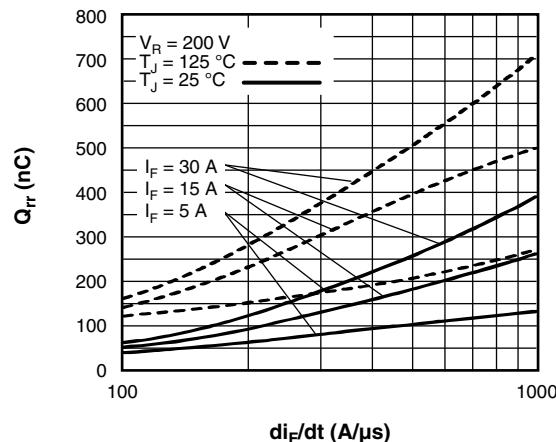


Fig. 7 - Typical Stored Charge vs.  $di_F/dt$

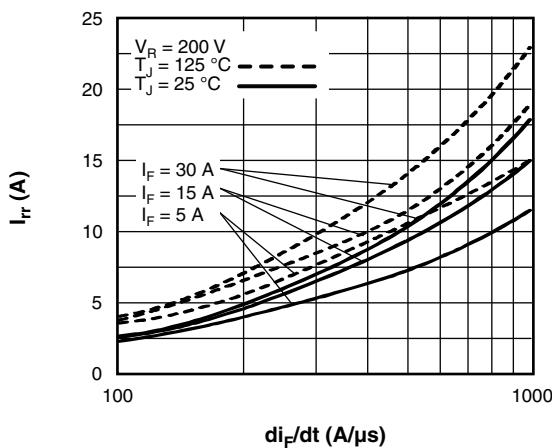


Fig. 6 - Typical Recovery Current vs.  $di_F/dt$

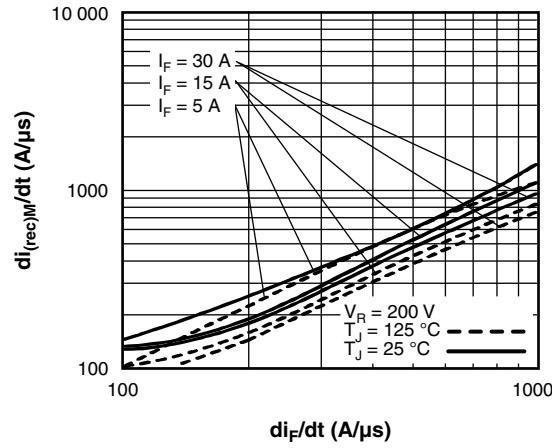
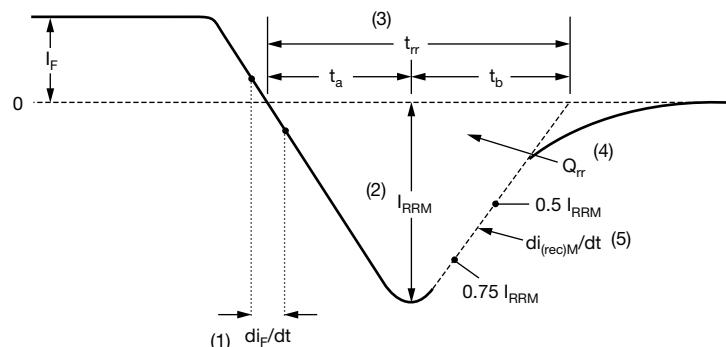


Fig. 8 - Typical  $di_{(rec)M}/dt$  vs.  $di_F/dt$



(1)  $di_F/dt$  - rate of change of current through zero crossing

(2)  $I_{RRM}$  - peak reverse recovery current

(3)  $t_{rr}$  - reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through  $0.75 I_{RRM}$  and  $0.5 I_{RRM}$  extrapolated to zero current.

(4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$  and  $I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$

Fig. 9 - Reverse Recovery Waveform and Definitions

**ORDERING INFORMATION TABLE**

Device code	VS-	HF	A	15	TB	60	-M3
	1	2	3	4	5	6	7

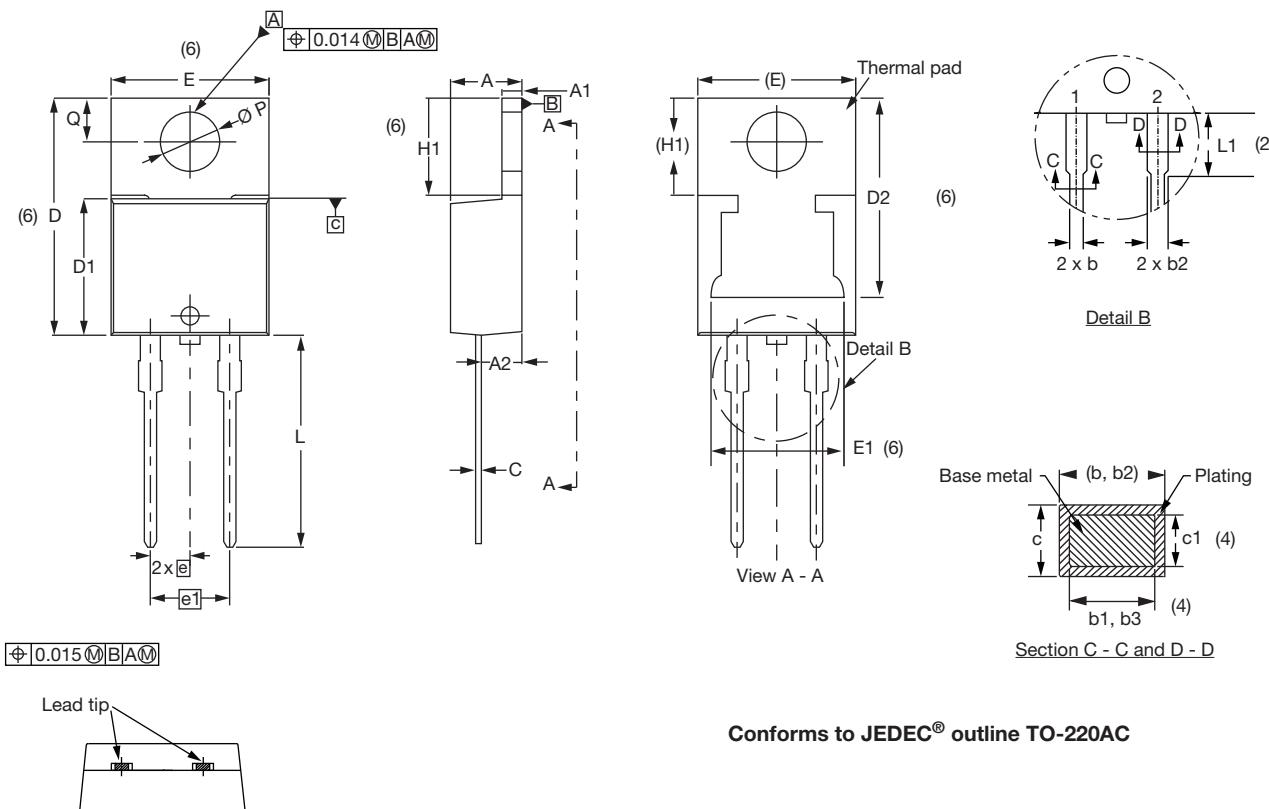
- 1** - Vishay Semiconductors product
- 2** - HEXFRED® family
- 3** - Electron irradiated
- 4** - Current rating (15 = 15 A)
- 5** - Package:  
TB = 2L TO-220AC
- 6** - Voltage rating (60 = 600 V)
- 7** - Environmental digit:  
-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

<b>ORDERING INFORMATION</b> (Example)		
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION
VS-HFA15TB60-M3	50	Antistatic plastic tube

<b>LINKS TO RELATED DOCUMENTS</b>	
Dimensions	<a href="http://www.vishay.com/doc?96156">www.vishay.com/doc?96156</a>
Part marking information	<a href="http://www.vishay.com/doc?95391">www.vishay.com/doc?95391</a>

## 2L TO-220AC

**DIMENSIONS** in millimeters and inches



Conforms to JEDEC® outline TO-220AC

## Notes

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2

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